 This work is protected by
US copyright laws and is for
instructors' use only.

Instructor's Resource Manual
to accompany

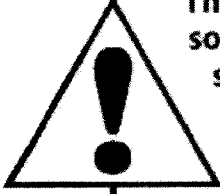
Introductory Electronic Devices and Circuits

Seventh Edition

Robert T. Paynter



Upper Saddle River, New Jersey
Columbus, Ohio



This work is protected by United States copyright laws and is provided solely for the use of instructors in teaching their courses and assessing student learning. Dissemination or sale of any part of this work (including on the World Wide Web) will destroy the integrity of the work and is not permitted. The work and materials from it should never be made available to students except by instructors using the accompanying text in their classes. All recipients of this work are expected to abide by these restrictions and to honor the intended pedagogical purposes and the needs of other instructors who rely on these materials.

Copyright © 2006 by Pearson Education, Inc., Upper Saddle River, New Jersey 07458.

Pearson Prentice Hall. All rights reserved. Printed in the United States of America. This publication is protected by Copyright and permission should be obtained from the publisher prior to any prohibited reproduction, storage in a retrieval system, or transmission in any form or by any means, electronic, mechanical, photocopying, recording, or likewise. For information regarding permission(s), write to: Rights and Permissions Department.

Pearson Prentice Hall™ is a trademark of Pearson Education, Inc.

Pearson® is a registered trademark of Pearson plc

Prentice Hall® is a registered trademark of Pearson Education, Inc.

Instructors of classes using Paynter, *Introductory Electronic Devices and Circuits, Seventh Edition*, may reproduce material from the instructor's resource manual for classroom use.

10 9 8 7 6 5 4 3 2 1



ISBN 0-13-173475-X

PRACTICE PROBLEM SOLUTIONS

CHAPTER 2

EXAMPLE PRACTICE PROBLEMS (CH 2)

- 2-1. The applied voltage is dropped across the reverse-biased diode. Therefore, $V_{R1} = V_{R2} = 0 \text{ V}$
- 2-2. Using the ideal model, $I_T = \frac{V_S}{R_T} = \frac{12 \text{ V}}{800 \Omega} = 15 \text{ mA}$
- 2-3. $V_R = V_S - 0.7 \text{ V} = 15 \text{ V} - 0.7 \text{ V} = 14.3 \text{ V}$
- 2-4. Using the practical model,

$$I_T = \frac{V_S - V_F}{R_T} = \frac{5 \text{ V} - 0.7 \text{ V}}{510 \Omega} = 8.43 \text{ mA}$$
- 2-5. $I_T = \frac{V_S - 0.7 \text{ V}}{R_T} = \frac{2 \text{ V} - 0.7 \text{ V}}{550 \Omega} = 2.36 \text{ mA}$
- 2-6. There are two forward-biased diodes. Therefore,

$$I_T = \frac{V_S - 1.4 \text{ V}}{R_T} = \frac{6 \text{ V} - 1.4 \text{ V}}{800 \Omega} = 5.75 \text{ mA}$$
- 2-7. Using the ideal model, $I_T = \frac{V_S}{R_T} = \frac{6 \text{ V}}{800 \Omega} = 7.5 \text{ mA}$
 Error (%) = $\frac{|5.75 \text{ mA} - 7.5 \text{ mA}|}{5.75 \text{ mA}} \times 100 = 30.4 \%$
- 2-8. $V_{pk} = 175 \text{ V}$. Adding a safety margin:
 $V_{RRM} = 175 \text{ V} \times 1.2 = 210 \text{ V}$. Thus, diodes 1N4004 through 1N4007 could be used in this circuit.
- 2-9. $I_F = \frac{100 \text{ V} - 0.7 \text{ V}}{51 \Omega} = 1.95 \text{ A}$. Adding a safety margin: $I_0 = 1.95 \text{ A} \times 1.2 = 2.34 \text{ A}$ (minimum)
- 2-10. $I_F = \frac{20 \text{ V} - 0.7 \text{ V}}{68 \Omega} = 284 \text{ mA}$
 $P_F = 284 \text{ mA} \times 0.7 \text{ V} = 199 \text{ mW}$. Adding a safety margin: $199 \text{ mW} \times 1.2 = 239 \text{ mW}$ (min)
- 2-11. $P_F = 750 \text{ mA} \times 0.7 \text{ V} = 525 \text{ mW}$. This exceeds the 500 mW rating.
- 2-12. $V_F = 0.7 \text{ V} + (12 \text{ mA} \times 8 \Omega) = 0.796 \text{ V}$
- 2-13. $I_{ZM} = \frac{P_{D(\max)}}{V_Z} = \frac{1 \text{ W}}{27 \text{ V}} = 37 \text{ mA}$
- 2-14. The derating value is found as (4.0 mW) (125°C–75°C) = 200 mW. Now, $P_{D(\max)}$ at 125°C is found as 500 mW – 200 mW = 300 mW.
- 2-15. The V_Z rating for the replacement component must be 75 V. The $P_{D(\max)}$ rating can be any value that is greater than or equal to 4 W. Only one diode in the figure fulfills both requirements: the 1N5374A.
- 2-16. $P_D = I_Z V_Z = (175 \text{ mA})(6.8 \text{ V}) = 1.19 \text{ W}$. The diode would need parameters of $V_Z = 6.8 \text{ V}$ and $P_D \geq 1.19 \text{ W}$. We could use the 1N5921A or 1N5342A.

- 2-17. The *minimum* value of V_F is used.

$$R_S = \frac{V_{\text{out(pk)}} - V_F}{I_F} = \frac{14 \text{ V} - 1.4 \text{ V}}{20 \text{ mA}} = 630 \Omega. \text{ The}$$

lowest standard value above 630 Ω is 680 Ω .

PRACTICE PROBLEMS (CH 2)

- The three components are in series, with the diode pointing toward the negative (–) side of the source.
- EFV: The arrow should point in the direction of electron flow (*against* the diode arrow). CFV: The arrow should point in the direction of conventional current (*in the direction indicated by the arrow*.)
- The three components are in series, with the diode pointing toward the positive (+) side of the source.
- In figures (a) and (c), the diodes are reverse biased; $I = 0$. In figure (b), the diode is forward biased. Electron flow is *against the arrow*. Conventional flow is *with the arrow*.
- In Figure 2.45a, D_1 is reverse biased and D_2 is forward biased. Both diodes in the other two figures are forward biased. For each conducting diode, electron flow is *against the arrow* and conventional flow is *with the arrow*.
- (a) D_1 is reverse biased, so $V_{D1} = V_S = 6 \text{ V}$.
 (b) D_1 is forward biased, so $V_{D1} = 0 \text{ V}$ (ideal).
 (c) D_1 is reverse biased, so $V_{D1} = V_S = 3 \text{ V}$ (ignoring the source polarity).
- D_1 is reverse biased; therefore, $V_{D1} = V_S = 10 \text{ V}$ and $V_{R1} = 0 \text{ V}$. D_2 is forward biased; therefore, $V_{D2} = 0 \text{ V}$ and $V_{R2} = 10 \text{ V}$.
- $V_{D1} = V_S = 6 \text{ V}$, $V_{R1} = 0 \text{ V}$, $I_T = 0 \text{ A}$
- $V_{D1} = 0.7 \text{ V}$, $V_{R1} = V_S - V_F = 1 \text{ V} - 0.7 \text{ V} = 0.3 \text{ V}$,

$$I_T = \frac{V_S - V_F}{R_1} = \frac{0.3 \text{ V}}{100 \Omega} = 3 \text{ mA}$$
- $V_{D1} = V_S = 3 \text{ V}$, $V_{R1} = V_{R2} = 0 \text{ V}$, $I_T = 0 \text{ A}$
- $V_{D1} = V_S = 10 \text{ V}$, $V_{R1} = 0 \text{ V}$, $I_1 = 0 \text{ A}$, $V_{D2} = 0.7 \text{ V}$,
 $V_{R2} = V_S - V_F = 9.3 \text{ V}$,

$$I_2 = \frac{V_S - V_F}{R_2} = \frac{9.3 \text{ V}}{1.8 \text{ k}\Omega} = 5.17 \text{ mA}$$
- There are *two* forward biased diodes, so
 $V_{R1} = V_S - (V_{D1} + V_{D2}) = 5 \text{ V} - 1.4 \text{ V} = 3.6 \text{ V}$ and

$$I_T = \frac{V_S - 1.4 \text{ V}}{R_1} = \frac{3.6 \text{ V}}{200 \Omega} = 18 \text{ mA}$$
- There are two forward-biased diodes, $V_{D1} = V_{D2} = 0.7 \text{ V}$, $I_T = \frac{V_S - 1.4 \text{ V}}{R_T} = \frac{9 \text{ V} - 1.4 \text{ V}}{300 \Omega} = \frac{7.6 \text{ V}}{300 \Omega} = 25.3 \text{ mA}$, $V_{R1} = I_T R_1 = (25.3 \text{ mA})(100 \Omega) = 2.53 \text{ V}$,
 $V_{R2} = I_T R_2 = (25.3 \text{ mA})(200 \Omega) = 5.06 \text{ V}$
- % of error = $\frac{|13.2 \text{ V} - 12.8 \text{ V}|}{13.2 \text{ V}} \times 100 = 3.03 \%$

15. $\text{Error (\%)} = \frac{|880 \mu\text{A} - 750 \mu\text{A}|}{880 \mu\text{A}} \times 100 = 14.8 \%$
This error is not acceptable.
16. $\text{Error (\%)} = \frac{|160 \text{ mV} - 144 \text{ mV}|}{160 \text{ mV}} \times 100 = 10\%$ This error is acceptable.
17. $I_T = \frac{V_S - 1.4 \text{ V}}{R_1 + R_2} = \frac{5 \text{ V} - 1.4 \text{ V}}{300 \Omega} = 12 \text{ mA}$ and
 $V_{R2} = I_T R_2 = (12 \text{ mA})(200 \Omega) = 2.4 \text{ V}$ The meter is measuring 2.54 V, and
 $\text{Error (\%)} = \frac{|2.54 \text{ V} - 2.4 \text{ V}|}{2.54 \text{ V}} \times 100 = 5.51 \%$
18. $I_T = \frac{V_S - 2.1 \text{ V}}{R_1 + R_2 + R_3} = \frac{5 \text{ V} - 2.1 \text{ V}}{340 \Omega} = 8.53 \text{ mA}$ and
 $V_{R2} = I_T R_2 = (8.53 \text{ mA})(120 \Omega) = 1.02 \text{ V}$. The meter is measuring 970 mV, and
 $\text{Error (\%)} = \frac{|970 \text{ mV} - 1.02 \text{ V}|}{970 \text{ mV}} \times 100 = 5.15 \%$
19. To provide a safety margin, the minimum value of V_{RRM} is found as $V_{RRM} = 1.2 V_{S(pk)} = (1.2)(100 \text{ V}) = 120 \text{ V}$.
20. The maximum reverse voltage across D_1 equals the peak value of V_{R2} , found as
 $V_{R2} = V_S \frac{R_2}{R_T} = (100 \text{ V}_{pk}) \frac{5 \text{ k}\Omega}{10 \text{ k}\Omega} = 50 \text{ V}$.
Providing a safety margin, the minimum value of V_{RRM} is found as $V_{RRM} = 1.2 V_{R2(pk)} = (1.2)(50 \text{ V}) = 60 \text{ V}$.
21. The maximum reverse voltage across D_1 equals the negative peak value of V_{R2} , found as
 $V_{R2} = V_S \frac{R_2}{R_T} = (-200 \text{ V}_{pk}) \frac{8.2 \text{ k}\Omega}{9.2 \text{ k}\Omega} = -178 \text{ V}$.
Providing a safety margin, the minimum value of V_{RRM} is found as $1.2 V_{R2(pk)} = (1.2)(-178 \text{ V}) = 214 \text{ V}$. The minimum practical value of V_{RRM} greater than 214 V is 250 V.
22. $I_F = \frac{V_S - V_F}{R_1} = \frac{50 \text{ V} - 0.7 \text{ V}}{5.1 \text{ k}\Omega} = 9.67 \text{ mA}$, and
 $I_0 = 9.67 \text{ mA} \times 1.2 = 11.6 \text{ mA}$ (minimum)
23. From problem 22, $I_F = 9.67 \text{ mA}$. $P_F = I_T V_F = (9.67 \text{ mA})(0.7 \text{ V}) = 6.77 \text{ mW}$. Providing a safety margin, $P_{D(max)} = 1.2 P_F = (1.2)(6.77 \text{ mW}) = 8.12 \text{ mW}$ (minimum).
24. $I_0 = \frac{P_{D(max)}}{V_F} = \frac{1.2 \text{ W}}{0.7 \text{ V}} = 1.71 \text{ A}$. Providing a safety margin, $I_F = 0.8 I_0 = (0.8)(1.71 \text{ A}) = 1.37 \text{ A}$ (maximum).
25. $I_0 = \frac{P_{D(max)}}{V_F} = \frac{750 \text{ mW}}{0.7 \text{ V}} = 1.07 \text{ A}$. Providing a safety margin $I_F = 0.8 I_0 = (0.8)(1.07 \text{ A}) = 856 \text{ mA}$ (maximum).
26. $V_F = 0.7 \text{ V} + I_F R_B = 0.7 \text{ V} + (10 \text{ mA})(5 \Omega) = 0.75 \text{ V}$
27. $V_F = 0.7 \text{ V} + I_F R_B = 0.7 \text{ V} + (8.2 \text{ mA})(12 \Omega) = 0.798 \text{ V}$
28. Equation (2.5) is transposed to obtain
 $I_F = \frac{V_F - 0.7 \text{ V}}{R_B}$ For $V_F = 0.8 \text{ V}$:
 $I_F = \frac{0.8 \text{ V} - 0.7 \text{ V}}{20 \Omega} = 5 \text{ mA}$
29. $V_R = I_R R_1 = (10 \mu\text{A})(10 \text{ k}\Omega) = 100 \text{ mV}$
30. The peak reverse value of V_S is 100 V. Providing a safety margin, $V_{RRM} \geq (1.2)(100 \text{ V}) = 120 \text{ V}$. Thus, any diode from 1N5402 through 1N5408 could be used.
31. Under *electrical characteristics*, the maximum reverse current is shown to be 100 μA (rated at $T = 150^\circ\text{C}$).
32. The surge current rating is the same for all diodes in the series: 200 A for 1 cycle.
33. The minimum V_{RRM} rating is found as $225 \text{ V} \times 1.2 = 270 \text{ V}$. The minimum I_0 rating is found as $24.5 \text{ A} \times 1.2 = 29.4 \text{ A}$. From Figure 2.27, the 1N3495 has these minimum acceptable ratings.
34. The minimum V_{RRM} rating is found as $170 \text{ V} \times 1.2 = 204 \text{ V}$. The minimum I_0 rating is found as $3.6 \text{ A} \times 1.2 = 4.32 \text{ A}$. From Figure 2.27, the MR754 has these minimum acceptable ratings.
35. The minimum V_{RRM} is $470 \text{ V} \times 1.2 = 564 \text{ V}$. The minimum I_0 rating is found as $\frac{2.8 \text{ W}}{0.7 \text{ V}} \times 1.2 = 4.8 \text{ A}$.
From Figure 2.27, the MR756 has these minimum acceptable ratings.
36. $Z_Z = \frac{\Delta V_Z}{\Delta I_Z} = \frac{25 \text{ mV}}{1 \text{ mA}} = 25 \Omega$
37. Figures (a), (c), (d), and (e) are biased for normal zener operation. In each case, the device points to the (+) terminal of the source.
38. For each conducting diode, electron flow is with the arrow and conventional flow is against the arrow.
39. $I_{ZM} = \frac{P_{D(max)}}{V_Z} = \frac{1 \text{ W}}{6.8 \text{ V}} = 147 \text{ mA}$
40. $I_{ZM} = \frac{P_{D(max)}}{V_Z} = \frac{10 \text{ W}}{24 \text{ V}} = 417 \text{ mA}$
41. Derating value = $(8 \text{ mW}/^\circ\text{C})(120^\circ\text{C} - 50^\circ\text{C}) = 560 \text{ mW}$, P_D at $120^\circ\text{C} = 5 \text{ W} - 560 \text{ mW} = 4.44 \text{ W}$ (maximum)

42. Derating value = $(1.67 \text{ mW}/^\circ\text{C})(150^\circ\text{C} - 50^\circ\text{C}) = 167 \text{ mW}$, P_D at $150^\circ\text{C} = 250 \text{ mW} - 167 \text{ mW} = 83 \text{ mW}$ (maximum)
43. The lowest P_D rating $\geq 1.8 \text{ W}$ is 5 W . The only diode with ratings of $28\text{V}/5\text{W}$ is the 1N5362A.
44. The P_D ratings $\geq 1.2 \text{ W}$ are 1.5 W and 5 W . The diodes with these ratings and $V_Z = 6.8 \text{ V}$ are the 1N5921A and the 1N5342A. Either of these can be used.
45. $P_D = I_{ZM}V_Z = (150 \text{ mA})(12 \text{ V}) = 1.8 \text{ W}$ Providing a safety margin, $P_{D(\text{max})} = 1.2P_D = (1.2)(1.8 \text{ W}) = 2.16 \text{ W}$. From Figure 2.34, only the 1N5349A can be used in this application.
46. $R_{S(\text{min})} = \frac{V_{\text{out(pk)}} - V_F}{I_F} = \frac{20 \text{ V} - 1.5 \text{ V}}{18 \text{ mA}} = 1028 \Omega$
(Use $1.1 \text{ k}\Omega$ standard)
47. $R_{S(\text{min})} = \frac{V_{\text{out(pk)}} - V_F}{I_F} = \frac{32 \text{ V} - 1.6 \text{ V}}{20 \text{ mA}} = 1520 \Omega$
(Use $1.6 \text{ k}\Omega$ standard)
48. (a) Both readings are high. The diode is *open*.
(b) Good. (c) Good. (d) Both readings are low. The diode is *shorted*.
49. The diode is *good*.
50. V_R is always equal to V_S , so V_F is 0 V . This is the symptom of a *shorted* diode.
51. V_R is always 0 V , so V_F is always equal to V_S . Since this is true even when the diode is forward biased, the device is *open*.
52. The voltage across the resistor equals the difference between the source voltage (V_S) and the zener voltage (V_Z). Therefore,
$$I_T = \frac{V_S - V_Z}{R} = \frac{16 \text{ V} - 5.1 \text{ V}}{120 \Omega} = 90.8 \text{ mA}$$
53. $I_T = \frac{V_{R1}}{R_1} = \frac{9 \text{ V}}{820 \Omega} = 11 \text{ mA}$, and
 $P_Z = V_Z I_T = (12 \text{ V})(11 \text{ mA}) = 132 \text{ mW}$
54. Connect the ohmmeter so that it reverse-biases the diode. This effectively removes the diode from the circuit.
55. Derating value = $(6.67 \text{ mW}/^\circ\text{C})(150^\circ\text{C} - 50^\circ\text{C}) = 667 \text{ mW}$. At 150°C , $P_D = 1 \text{ W} - 667 \text{ mW} = 333 \text{ mW}$. The maximum current at that temp is found as $I_{ZM} = \frac{P_D}{V_Z} = \frac{333 \text{ mW}}{7.5 \text{ V}} = 44.4 \text{ mA}$
56. The 1N4738A has the following ratings: $V_Z = 8.2 \text{ V}$ and $P_D = 1 \text{ W}$. The derating factor for the device is $6.67 \text{ mW}/^\circ\text{C}$ for temperatures above 50°C . For the circuit in Figure 2.56,
$$I_T = \frac{V_S - V_Z}{R_1} = \frac{60 \text{ V} - 8.2 \text{ V}}{910 \Omega} = 56.9 \text{ mA}$$
 and

$P_D = V_Z I_T = (8.2 \text{ V})(56.9 \text{ mA}) \cong 467 \text{ mW}$. At $T = 150^\circ\text{C}$, the 1N4738A is limited to
 $P_{D(\text{max})} = 1 \text{ W} - (6.67 \text{ mW}/^\circ\text{C})(150^\circ\text{C} - 50^\circ\text{C}) = 1 \text{ W} - 667 \text{ mW} = 333 \text{ mW}$. Since this value is lower than the circuit requirement (467 mW), the component cannot be used.

57. According to the component spec sheet, the 1N5341 has a rating of $V_Z = 6.2 \text{ V}$ @ $I_{ZT} = 200 \text{ mA}$.

58. The power dissipation of the diode when operated at V_Z equals the product of V_Z and I_{ZT} , and varies from diode to diode. For the 1N5364 (a 33 V , 5 W zener), $V_Z I_{ZT} = (33 \text{ V})(40 \text{ mA}) = 1.32 \text{ W}$. (Student results will likely vary from this value.)

59. Yellow light has a range of approximately 565 to 590 nanometers (nm). Yellow LEDs are rated somewhere in this range.

CHAPTER 3

EXAMPLE PRACTICE PROBLEMS (CH 3)

- 3-1. $I_S = \frac{N_P}{N_S} I_P = \left(\frac{1}{12}\right)(250 \text{ mA}) = 20.8 \text{ mA}$
- 3-2. $V_{S(\text{pk})} = \frac{N_S}{N_P} V_{P(\text{pk})} = \left(\frac{1}{10}\right)(180 \text{ V}) = 18 \text{ V}$,
 $V_{L(\text{pk})} = V_{S(\text{pk})} - 0.7 \text{ V} = 18 \text{ V} - 0.7 \text{ V} = 17.3 \text{ V}$
- 3-3. $V_{S(\text{pk})} = \frac{V_{S(\text{rms})}}{0.707} = \frac{12 \text{ V}}{0.707} = 17 \text{ V}$, $V_{L(\text{pk})} = V_{S(\text{pk})} - V_F = 17 \text{ V} - 0.7 \text{ V} = 16.3 \text{ V}$
- 3-4. $V_{P(\text{pk})} = \frac{120 \text{ V}}{0.707} = 170 \text{ V}$
 $V_{S(\text{pk})} = \frac{N_S}{N_P} V_{P(\text{pk})} = \left(\frac{1}{12}\right)(170 \text{ V}) = 14.2 \text{ V}$
 $V_{L(\text{pk})} = V_{S(\text{pk})} - 0.7 \text{ V} = 13.5 \text{ V}$
 $I_{L(\text{pk})} = \frac{V_{L(\text{pk})}}{R_L} = \frac{13.5 \text{ V}}{8.2 \text{ k}\Omega} = 1.65 \text{ mA}$
- 3-5. $V_{P(\text{pk})} = \frac{120 \text{ V}}{0.707} = 170 \text{ V}$
 $V_{S(\text{pk})} = \frac{N_S}{N_P} V_{P(\text{pk})} = \left(\frac{1}{14}\right)(170 \text{ V}) = 12.1 \text{ V}$
 $V_{L(\text{pk})} = V_{S(\text{pk})} - 0.7 \text{ V} = 11.4 \text{ V}$
 $V_{\text{ave}} = \frac{V_{L(\text{pk})}}{\pi} = \frac{11.4 \text{ V}}{\pi} = 3.63 \text{ V}$
- 3-6. $I_{\text{ave}} = \frac{V_{\text{ave}}}{R_L} = \frac{24 \text{ V}}{2.2 \text{ k}\Omega} = 10.9 \text{ mA}$
- 3-7. $V_{S(\text{pk})} = \frac{48 \text{ V}}{0.707} = 67.9 \text{ V}$, $V_{L(\text{pk})} = V_{S(\text{pk})} - 0.7 \text{ V} = 67.9 \text{ V} - 0.7 \text{ V} = 67.2 \text{ V}$